

**Features**

- AEC-Q101 Qualified
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low  $R_{DS(ON)}$
- Moisture Sencitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

**Maximum Ratings**

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 5H°C/W Junction to Ambient (Note 2)
- Thermal Resistance: FE°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	F€0	V
Gate-Source Volltage	$V_{GS}$	±20	V
Continuous Drain Current	$I_D$	$T_C=25^\circ C$	100
		$T_C=100^\circ C$	63
Pulsed Drain Current (Note 3)	$I_{DM}$	H 0	A
Total Power Dissipation (Note 4)	$P_D$	FFH	W
Single Pulsed Avalanche Energy (Note 5)	$E_{AS}$	4€0	mJ

Note:

F€Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

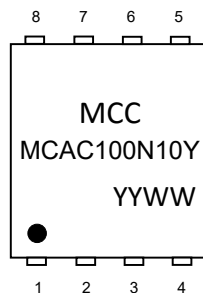
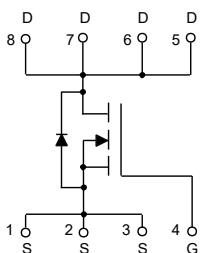
G€The value of  $R_{\theta JA}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ C$ .

H€Repetitive rating; pulse width limited by max. junction temperature.

I€ $P_D$  is based on max. junction temperature, using junction-case thermal resistance.

Í EV, R M C EX, 00 M EX, 0 MF EX, 0 MG EX, 0 PE

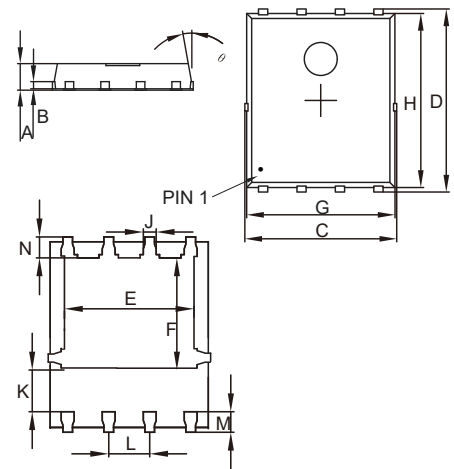
**Internal Structure and Marking Code**



4 codes in total  
YY is the year  
WW is the

**N-CHANNEL MOSFET**

**DFN5060**



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.031	0.047	0.80	1.20	
B	0.010		0.254		TYP.
C	0.193	0.222	4.90	5.64	
D	0.232	0.250	5.90	6.35	
E	0.148	0.167	3.75	4.25	
F	0.126	0.154	3.20	3.92	
G	0.189	0.213	4.80	5.40	
H	0.222	0.239	5.65	6.06	
K	0.045	0.059	1.15	1.50	
J	0.012	0.020	0.30	0.50	
L	0.046	0.054	1.17	1.37	
M	0.012	0.028	0.30	0.71	
N	0.016	0.028	0.40	0.71	

**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	$F_{\infty}$			V
Gate-Source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=100V, V_{GS}=0V$			1	$\mu A$
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	G	H	I	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=20A$		I	I	m $\Omega$
		$V_{GS}=1V, I_D=30A$		I	I	
Gate Resistance	$R_g$	f=1 MHz, Open drain		$\infty$		$\Omega$
<b>Diode Characteristics</b>						
Continuous Body Diode Current	$I_S$				100	A
Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=18A$		0.8	1.2	V
Reverse Recovery Time	$t_{rr}$	$I_F=1A, dI_F/dt=30A/\mu s$		I		ns
Reverse Recovery Charge	$Q_{rr}$			I		nC
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V, f=1MHz$		I		pF
Output Capacitance	$C_{oss}$			G		
Reverse Transfer Capacitance	$C_{rss}$			I		
Total Gate Charge	$Q_g$	$V_{DS}=10V, V_{GS}=10V, I_D=1A$		I		nC
Gate-Source Charge	$Q_{gs}$			F		
Gate-Drain Charge	$Q_{gd}$			F		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, V_{GS}=10V, R_{GEN}=30\Omega, I_{DS}=1A$		G		ns
Turn-On Rise Time	$t_r$			FG		
Turn-Off Delay Time	$t_{d(off)}$			H		
Turn-Off Fall Time	$t_f$			I		

**Curve Characteristics**

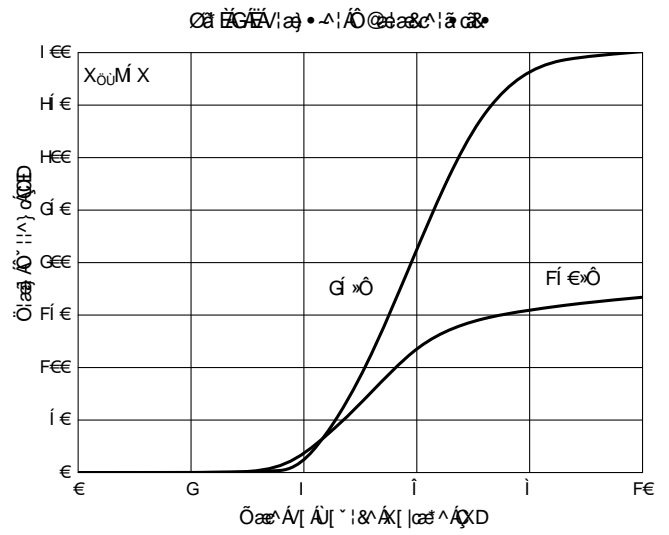
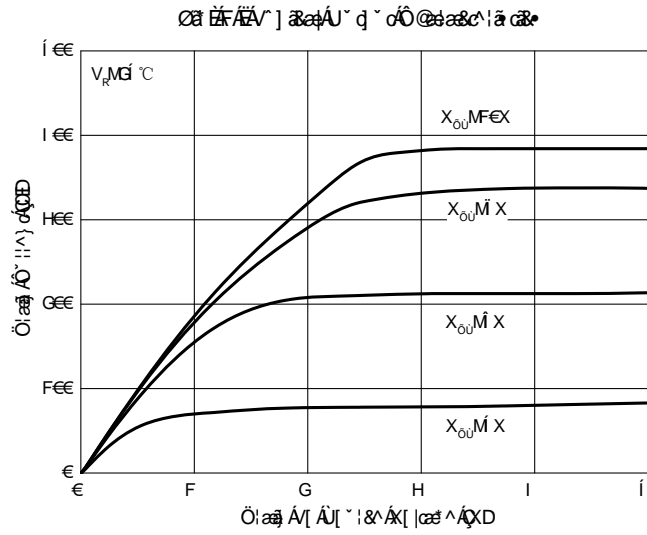


Fig. 4 - Normalized On Resistance Characteristics

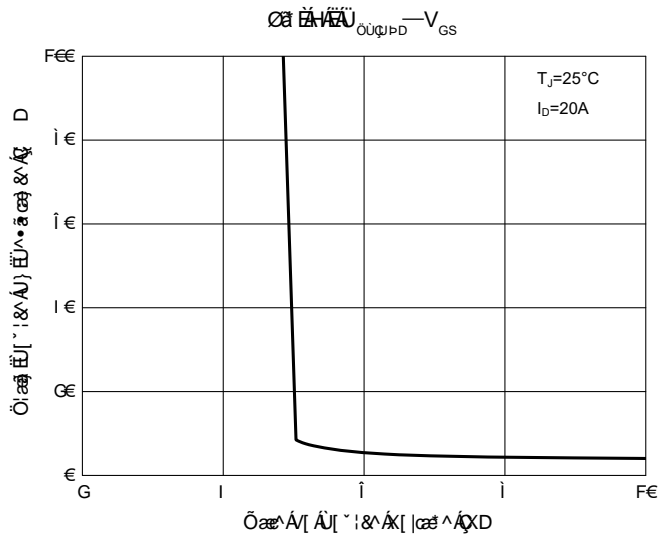


Fig. 5 - Capacitance Characteristics

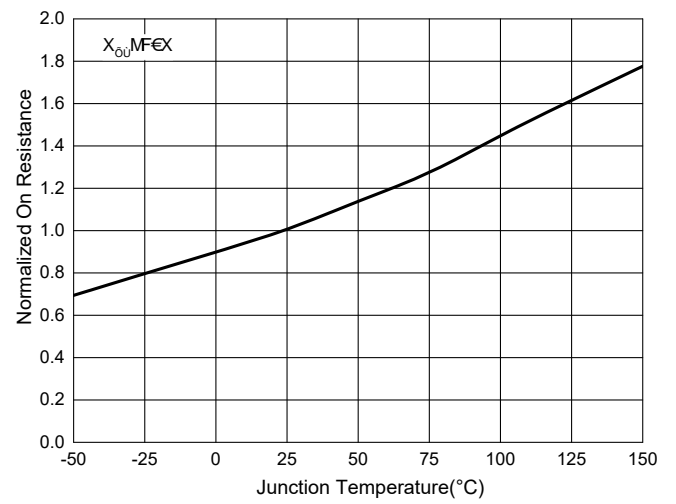
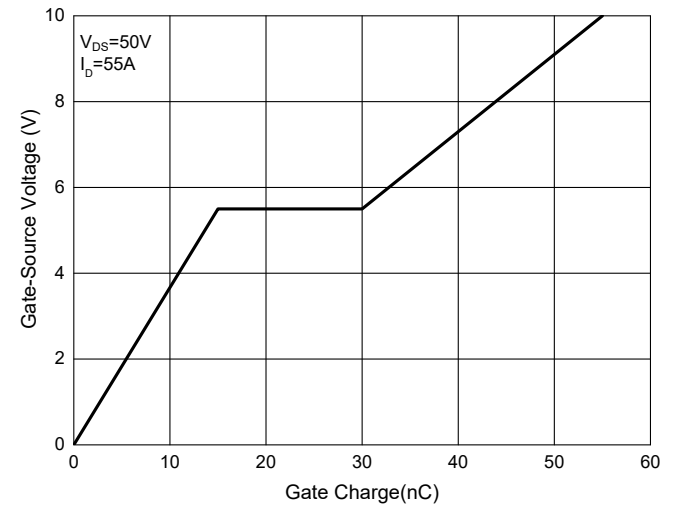


Fig. 6 - Gate Charge



**Curve Characteristics**

Fig. 7 -  $R_{DS(ON)} - I_D$

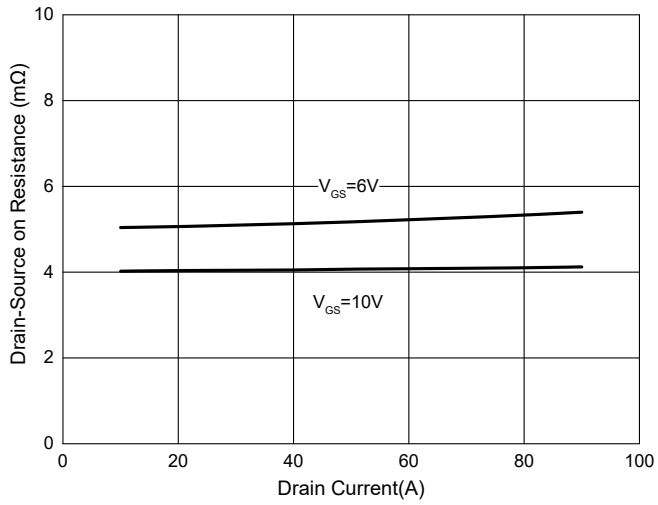


Fig. 8 - Normalized Threshold voltage

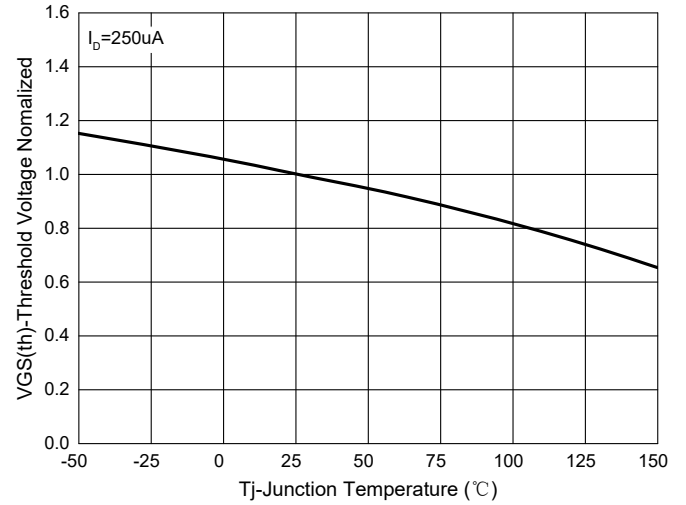


Fig. 9 -  $I_S - V_{SD}$

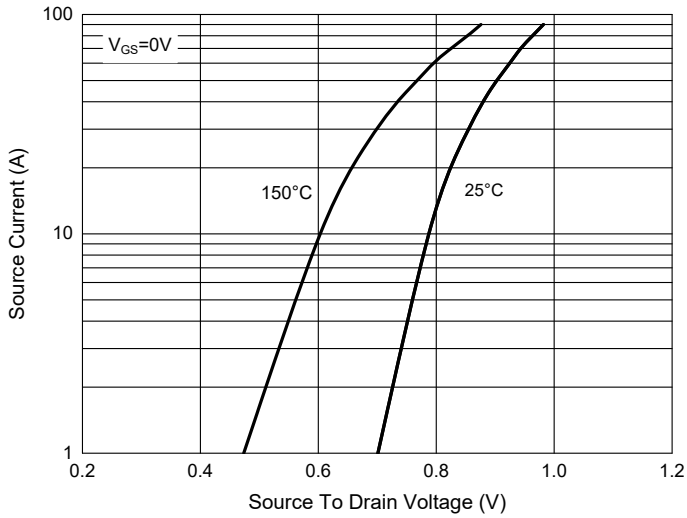


Fig. 10 - Current dissipation

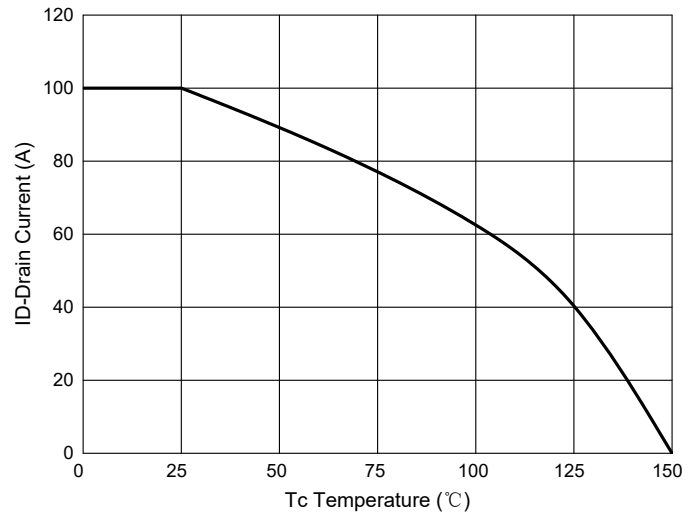
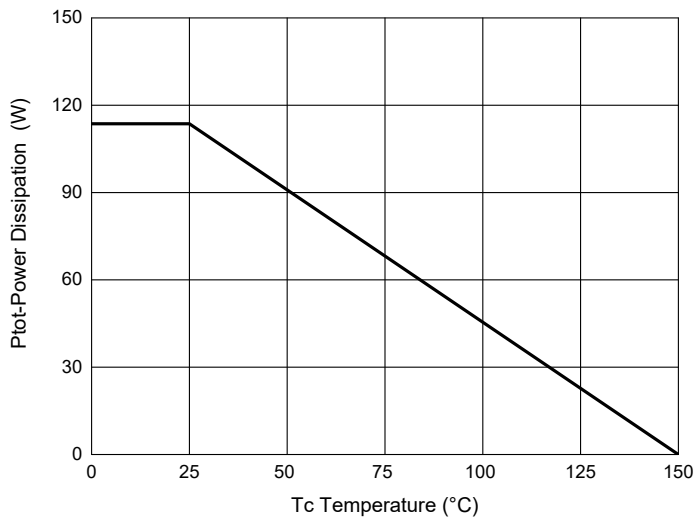


Fig. 11 - PD dissipation



**Curve Characteristics**

Fig. 12 - Safe Operation Area

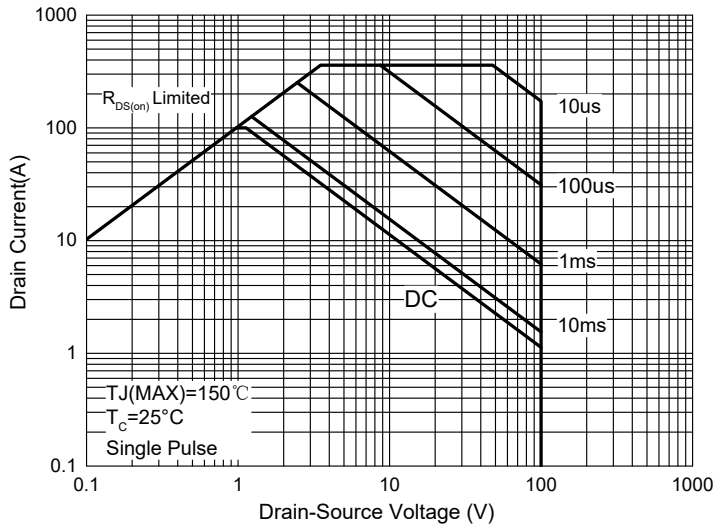
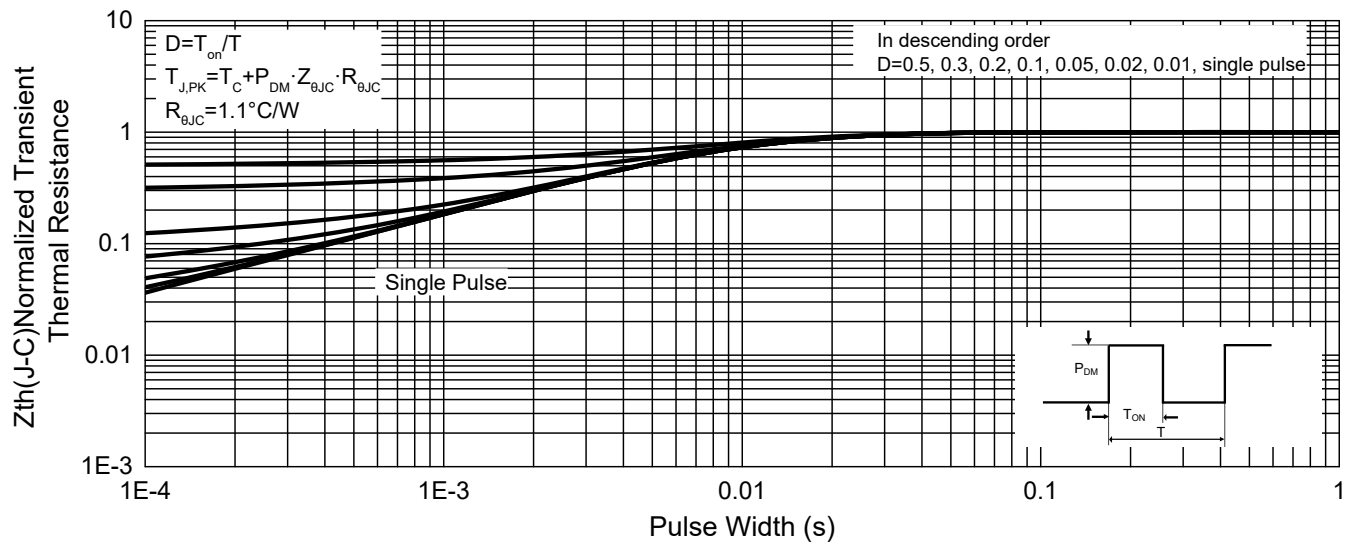


Fig. 13 - Normalized Transient Thermal Impedance



## Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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